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FORM 1449* INFORMATION DISCLOSURE STATEMENT IN AN APPLICATION (Use several sheets if necessary)	Docket Number: 10873.1384US01	Application Number: 10/758815
	Applicant: KITAOKA, et al.	
	Filing Date: January 16, 2004	Group Art Unit: 2813

U.S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NO.	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE

FOREIGN PATENT DOCUMENTS

	DOCUMENT NO.	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
						YES	NO

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

		Bohyama, et al., "Distribution of Threading Dislocations in Epitaxial Lateral Overgrowth GaN by Hydride Vapor-Phase Epitaxy Using Mixed Carrier Gas of H_2 and N_2", Jpn. J. Appl. Phys., vol. 41 (2002), pp. 75-76, Part 1, No. 1, January 2002
		Yoshimoto, et al., "Low-Temperature Microscopic Photoluminescence Images of Epitaxially Laterally Overgrown GaN", Jpn. J. Appl. Phys., vol. 40 (2001), pp. L386-L388, Part 2, no. 4B, 15 April 2001

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EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form for next communication to the Applicant.

*Substitute Disclosure Statement Form (PTO-1449) Patent and Trademark Office; U.S. DEPARTMENT OF COMMERCE